

TITLE OF THE INVENTION

First-In First-Out Memory System With Shift Register Fill Indication

CROSS-REFERENCES TO RELATED APPLICATIONS

[0001] This case is related to U.S. Patent Application _____, entitled
5 "First-In First-Out Memory System With Single Bit Collision Detection" (TI-36900), filed
on the same date as the present application.

STATEMENT REGARDING FEDERALLY SPONSORED RESEARCH OR
DEVELOPMENT

10 [0002] Not Applicable.

BACKGROUND OF THE INVENTION

[0003] The present embodiments relate to electronic devices and circuits and are more
particularly directed to such devices and circuits that include a first-in first-out ("FIFO")
15 memory system that includes shift registers from which a level of data fullness of the FIFO
is indicated.

[0004] Electronic circuits are prevalent in numerous applications, including those
used in personal, business, and other devices. Demands of the marketplace affect many
aspects of the design of these circuits, including factors such as device complexity, size,
20 and cost. Various of these electronic circuits include some aspect of digital signal
processing and, quite often, these circuits include storage devices that operate on a FIFO
basis. As is well-known in the art, such FIFO circuits are so named because data words
are read from the circuit in the same order as they were written to the circuit. As a storage

device, the FIFO is also sometimes referred to as a FIFO memory or a FIFO random access memory ("RAM"). Typically, a FIFO is a logical array for storing a number of data words. The size of each data word in the FIFO depends on the application and may be any number of bits, where 4 bits, 8 bits, 16 bits, and 32 bits are common examples, while any
5 number of bits per word may be implemented based on the application.

[0005] A FIFO has a number of word storage locations, and typically in the prior art any of these locations may be indicated, or "addressed," during operation of the FIFO by both a read pointer and a write pointer. Typically, the read pointer indicates the word storage location from which a next word will be read, and the write pointer indicates the
10 word storage location into which a next word will be written. The number of word storage locations in a given FIFO also is typically dictated at least in part by the application. In view of that application, the FIFO design is often determined in an effort to satisfy data requirements while minimizing this number of storage locations so as to avoid unnecessarily enlarging the FIFO. Typically, however, with the designed minimized
15 number of word storage locations, there is an expectation that the pointers may at some instance converge on one another. More specifically, if numerous read operations occur with corresponding advancement of the read pointer, while the write pointer does not advance or does not advance at approximately the same rate, then the read pointer will eventually indicate a word location near that of the write pointer. In this event, most of
20 the valid words in the FIFO have been read and, thus, the FIFO is said to be near empty, that is, it contains few remaining valid and unread words. Conversely, if numerous write operations occur with corresponding advancement of the write pointer, while the read pointer does not advance or does not advance at approximately the same rate, then the write pointer will eventually indicate a word location near that of the read pointer. In this
25 event, most of the word storage locations in the FIFO have been written and not read and, thus, the FIFO is said to be near full. In the prior art, circuits are often included to detect either or both of these two extremes because each may warrant a system response. For example, a response to either a near-empty or near-full FIFO may be to ready the system for possible invalid data or to control the data flow to alleviate the extreme. Also included

in the prior art is the ability to detect the middle state between these two extremes, that is, when the FIFO is half full of valid and unread words.

[0006] In an effort to respond to the level of fullness of a FIFO, whether that level detection may relate to near-empty, near-full, or half-full, the prior art has developed various systems based on the read and write pointers. In these systems, the prior art pointers are typically multiple-bit digital values that numerically identify each word storage location. For example, for an instance of a FIFO with locations 0 through $Z=2^N-1$, then both the read pointer and the write pointer consist of incrementing modulo counters with N bits that increment through the values of 0 through 2^N-1 and then start once more at 0 (or vice versa for decrementing counters). Often each such counter is referred to as a pointer vector in that each such vector has multiple bits, where at least one of those multiple bits, by definition, is a different value for each of the 2^N different addresses of the FIFO. Given this implementation of pointers, the prior art manner of detecting fullness typically compares the two pointers, where fullness may be detected if the pointers have counter values within a certain difference of one another. Thus, this difference may be evaluated using arithmetic computations such as through use of a comparator or subtracting unit, by ways of example. However, the present inventors have observed that in certain FIFOs, and particularly in asynchronous FIFOs, these techniques may become quite extensive. Specifically, in asynchronous FIFOs, a read may occur according to one timing domain that is independent of when a write may occur, that is, the read and write operations, and pointers, are asynchronous with respect to one another. As a result, as a necessary element of the pointer evaluation technique described above, the prior art also involves a complex manner of taking the value of one pointer into the clock domain of the other pointer so as to provide an accurate comparison of the two to avoid metastability problems. In other words, without such an action, there is a possibility that at the time a first pointer (e.g., read) is copied so as to be evaluated relative to a second pointer (e.g., write), the first pointer may be in the process of changing; further, since each pointer address is represented by a vector, and if that vector is changing at the time it is copied, then some bits in the vector may contain the value before the change while others contain the new value. In this case, the captured vector value would not just be either the

previous value or the new value but some totally unknown address instead. Thus, the prior art includes additional circuitry for attempting to accommodate this necessary crossing over of one pointer into the other pointer's time domain. This additional circuitry adds complexity, which consequently increases device size, cost, and power consumption, all of which are undesirable in circuit design, particularly in today's competitive marketplace.

[0007] In view of the above, the preferred embodiments as set forth below seek to improve upon the prior art as well as its associated drawbacks.

BRIEF SUMMARY OF THE INVENTION

[0008] In the preferred embodiment, there is an electronic device. The device comprises a memory structure comprising an integer M of word storage locations. The device further comprises a write shift register for storing a sequence of bits. The sequence
5 in the write shift register comprises a number of bits equal to a ratio of $1/R_1$ times the integer M . The device further comprises circuitry for providing a write clock cycle to the write shift register for selected write operations with respect to any of the word storage locations. In response to each write clock cycle, received from the circuitry for providing the write clock cycle, the write shift register shifts the sequence in the write shift register.
10 Further, one bit in the sequence in the write shift register corresponds to an indication of one of the memory word storage locations into which a word will be written. The device further comprises a read shift register for storing a sequence of bits. The sequence in the read shift register comprises a number of bits equal to a ratio of $1/R_2$ times the integer M . The device further comprises circuitry for providing a read clock cycle to the read shift
15 register for selected read operations with respect to any of the word storage locations. In response to each read clock cycle, received from the circuitry for providing the read clock cycle, the read shift register shifts the sequence in the read shift register. Further, one bit in the sequence in the read shift register corresponds to an indication of one of the memory word storage locations from which a word will be read. Lastly, the device
20 comprises circuitry for evaluating selected bits in the sequence in the write register relative to selected bits in the sequence in the read register for detecting a level of data fullness in the memory structure.

[0009] Other aspects are also disclosed and claimed.

BRIEF DESCRIPTION OF THE SEVERAL VIEWS OF THE DRAWING

[0010] Figure 1a illustrates a block diagram of a portion of the data storage system according to the preferred embodiments.

5 [0011] Figure 1b illustrates the block diagram of Figure 1a with an example of the advancement of the shift register bits and corresponding FIFO read and write pointers.

[0012] Figure 2 illustrates the block diagram of Figure 1a with additional aspects directed to detecting fullness, either in the form of near-full or near-empty status, in the system FIFO.

10 [0013] Figure 3 illustrates sequential operations of the preferred embodiment of Figure 2 where the read shift register SR_{RD} advances toward the write shift register SR_{WT} as the FIFO approaches an empty state.

[0014] Figure 4 illustrates sequential operations of the preferred embodiment of Figure 2 where the write shift register SR_{WT} advances toward the read shift register SR_{RD} as the FIFO approaches a full state.

15 [0015] Figure 5 illustrates the block diagram of Figure 1a with additional aspects directed to detecting fullness in the system FIFO, as an alternative to the system of Figure 2.

[0016] Figure 6 illustrates sequential operations of the alternative preferred embodiment of Figure 5 where the read shift register SR_{RD} advances toward the write shift register SR_{WT} as the FIFO approaches an empty state.

[0017] Figure 7 illustrates sequential operations of the alternative preferred embodiment of Figure 5 where the write shift register SR_{WT} advances toward the read shift register SR_{RD} as the FIFO approaches an empty state.

25 [0018] Figure 8 illustrates the block diagram of Figure 1a with additional aspects directed to detecting half-fullness in the system FIFO.

[0019] Figure 9 illustrates sequential operations of the preferred embodiment of Figure 8 where the read shift register SR_{RD} advances relative to the write shift register SR_{WT} .

[0020] Figure 10 illustrates the block diagram of Figure 1a with additional aspects
5 directed to detecting fullness in the system FIFO, as an alternative to the systems of Figures 2 and 5.

DETAILED DESCRIPTION OF THE INVENTION

[0021] Figure 1a illustrates a block diagram of a data storage system designated generally at 10 according to the preferred embodiments, where certain preferred aspects of system 10 are not shown but are added in later figures so as to simplify the present discussion. In one preferred embodiment, system 10 is constructed using a single integrated circuit. Additional circuitry may be included within such an integrated circuit such as circuitry that uses the data stored in system 10. However, to simplify the present illustration and discussion, such additional circuitry is neither shown nor described. Moreover, system 10 may be implemented in connection with numerous digital data systems, where one skilled in the art may ascertain such systems.

[0022] Looking to the blocks in system 10, system 10 includes various items which in general are known in the prior art, but additional fullness-detection aspects as well as related control and operation distinguishes the overall system as detailed later. Looking by way of introduction to some of the blocks that are comparable to the prior art, they include a first-in first-out ("FIFO") memory 12 having a number M of word storage locations; by way of example, $M=8$ such storage locations are shown and designated SL0 through SL7 and, thus, M also may be represented as $2^N=2^3=M$. However, the choice of $N=3$ and $M=8$ is only by way of illustration and one skilled in the art will recognize that the inventive teachings of this document may be implemented in different sized FIFO devices. In the preferred embodiment, each storage location SL_x has a same B -bit dimension, where that dimension may be any size. Also included in system 10 are a write pointer PTR_{WT} and a read pointer PTR_{RD} . Write pointer PTR_{WT} indicates the word storage location of FIFO memory 12 into which a next word will be written. Read pointer PTR_{RD} indicates the word storage location of FIFO memory 12 from which a next word will be read. As detailed below, however, the advancement of each such pointer is either indicated or tracked in a novel manner consistent with the preferred embodiments. System 10 also includes a data read/write circuit 14 that is bi-directionally connected to each word storage location in FIFO memory 12. Thus, data to be written to FIFO memory 12 is provided to an input 14_i of data read/write circuit 14 and is written to the storage

location indicated by write pointer PTR_{WT} , and data when read out of FIFO memory 12 from a location indicated by read pointer PTR_{RD} is provided at output 14_O of data read/write circuit 14. Data read/write circuit 14 may be constructed in various manners.

[0023] Turning now to aspects of system 10 as part of the overall inventive structure, system 10 includes a controller 16 coupled to data read/write circuit 14. In addition, controller 16 provides a write clock signal CLK_{WT} to a write shift register SR_{WT} and a read clock signal CLK_{RD} to a read shift register SR_{RD} . In the preferred embodiment, each shift register SR_{WT} and SR_{RD} is M bits in length, that is, it is the same number in bits as the number of word storage locations in FIFO memory 12. Preferably, each shift register SR_{WT} and SR_{RD} also is a wraparound device, that is, in response to a respective clock signal each register shifts each bit of its contents one location toward its most significant bit ("MSB") and the bit stored at its MSB location wraps around to the least significant bit ("LSB") location as is known in the shift register art. This wraparound functionality of each shift register is shown in Figure 1a by way of respective dotted arrows from the MSB to the LSB of each shift register. Lastly, note that for sake of convention, the bit locations are shown in Figure 1a to the left of the Figure, and those locations also will be referenced in this document as $SR_{WT}[x]$ and $SR_{RD}[x]$, where the value x may be any of the bit locations. For example, the LSB of each shift register is $SR_{WT}[0]$ and $SR_{RD}[0]$, the next most significant bit location above that LSB is $SR_{WT}[1]$ and $SR_{RD}[1]$, and so forth.

[0024] As further explored below, in one preferred embodiment, at least one bit in each shift register SR_{WT} and SR_{RD} is loaded with one binary value of one, while the majority of the remaining bits of the shift register are loaded with a binary value of zero. In operation, the particular binary value of a one in this regard corresponds to the pointer for the respective shift register. Looking at this aspect with respect to write shift register SR_{WT} , the sole binary value of one in it corresponds to the location of write pointer PTR_{WT} . In the example of Figure 1a, therefore, the sole binary value of one in write shift register SR_{WT} is located at its bit location $SR_{WT}[4]$, and this value corresponds to the location of write pointer PTR_{WT} which identifies word storage location $SL4$ in FIFO memory 12. This relationship is further indicated in Figure 1a by a dashed arrow, labeled PTR_{WT} , from the

binary one in write shift register SR_{WT} as a pointer to the corresponding word storage location in FIFO memory 12. Note, therefore, that write shift register SR_{WT} corresponds to write pointer PTR_{WT} in that it may be used to directly provide write pointer PTR_{WT} , or in an alternative embodiment that pointer may be provided by a separate circuit, including a counter, whereby at the same time that the separate circuit is advanced by write clock CLK_{WT} , so is the shifted value in write shift register SR_{WT} , so that in all instances the location of the binary one in write shift register SR_{WT} tracks and corresponds to the then-indicated word storage location in FIFO memory 12 by write pointer PTR_{WT} . Looking at the same binary loading aspect described above but now in connection with read shift register SR_{RD} , the sole binary value of one in it corresponds to the location of read pointer PTR_{RD} . In the example of Figure 1a, therefore, the sole binary value of one in read shift register SR_{RD} is located at its bit location of $SR_{RD}[0]$, and this value corresponds to the location of read pointer PTR_{RD} which identifies word storage location $SL0$ in FIFO memory 12. This relationship is further indicated in Figure 1a by a dashed arrow, labeled PTR_{RD} , from the binary one in read shift register SR_{RD} as a pointer to the corresponding word storage location in FIFO memory 12. Thus, read shift register SR_{RD} corresponds to read pointer PTR_{RD} in that it may be used to directly provide read pointer PTR_{RD} , or in an alternative embodiment that pointer may be provided by a separate circuit, including a counter, whereby at the same time that the separate circuit is advanced by read clock CLK_{RD} , so is the shifted value in read shift register SR_{RD} , so that in all instances the location of the binary one in read shift register SR_{RD} tracks and corresponds to the then-indicated word storage location in FIFO memory 12 by read pointer PTR_{RD} . These aspects are further explored in the remainder of this document.

[0025] Figure 1b illustrates the block diagram of Figure 1a with an example of the advancement of the shift register bits and corresponding FIFO read and write pointers. Specifically, Figure 1b illustrates system 10 following two cycles of write clock CLK_{WT} and one cycle of read clock CLK_{RD} , which is a possible scenario given the asynchronous nature of these two clocks with respect to one another. With reference to the two cycles of write clock CLK_{WT} , each period of write clock CLK_{WT} is provided by controller 16 to write shift register SR_{WT} . In response to each period, write shift register SR_{WT} shifts each bit it stores

one location toward its MSB, with a wraparound of the bit from its MSB to its LSB. Accordingly, the binary value of one shown in bit location $SR_{WT}[4]$ of Figure 1a is shifted, in response to the two clock cycles of write clock CLK_{WT} , to location $SR_{WT}[6]$ in Figure 1b. Further, because write pointer PTR_{WT} is either directly provided, or tracked, by write shift register SR_{WT} , then Figure 1b also illustrates the advancement of write pointer PTR_{WT} to storage location SL6 in Figure 1b. With reference to the one cycle of read clock CLK_{RD} , the period of read clock CLK_{RD} is provided by controller 16 to read shift register SR_{RD} . In response, read shift register SR_{RD} shifts each bit it stores one location toward its MSB, with a wraparound of the bit from its MSB to its LSB. Accordingly, the binary value of one shown in location $SR_{RD}[0]$ of Figure 1a is shifted, in response to the one clock cycle of read clock CLK_{RD} , to location $SR_{RD}[1]$ in Figure 1b. Further, because read pointer PTR_{RD} is either directly provided, or tracked, by read shift register SR_{RD} , then Figure 1b also illustrates the advancement of read pointer PTR_{RD} to storage location SL1 in Figure 1b.

[0026] From the example of Figure 1b, one skilled in the art should appreciate the general nature of the advancement of shift register values and the corresponding advancement of pointers in system 10, with the remaining discussion pertaining to additional aspects directed to fullness detection in FIFO memory 12. However, before proceeding, note that the one-to-one correspondence of M bit locations in each shift register with the M word storage locations in FIFO memory 12 is only one preferred embodiment. In an alternative embodiment, each shift register may have a number of bit locations equal to a ratio $1/R$ of the M word storage slots in FIFO memory 12, where the value R could differ for each shift register. As an example with R equal to the same value for each shift register, and for $R=2$, FIFO memory 12 may have $M=64$ word storage locations while each shift register (or one such register) has $1/R * M = 1/2 * 64 = 32$ bit locations (i.e., in this case, the ratio is $1/2$). In any event, then the shift register shifts its binary sequence once every R times its corresponding pointer is advanced with respect to FIFO memory 12, where in the present example $R=2$ and, thus, the shift register shifts for every $R=2$ times the corresponding pointer is advanced. Note also that the example of Figure 1b, therefore, merely represents the instance where $R=1$, so both shift registers have $1/R = 1 * M$ bit locations, and each shift register shifts its binary sequence every time its

corresponding pointer is advanced with respect to FIFO memory 12 because $R=1$. These aspects will be further appreciated by one skilled in the art given the remaining discussion of this document, as well as the implications of how it might slightly affect the timing of a fullness detection. For sake of simplifying the discussion, however, the remaining
5 illustrations are directed to the instance where each shift register has a number of M bit locations and, thus, each such register shifts its binary pattern once for each advancement of its corresponding FIFO pointer.

[0027] The example of pointer position in Figure 1b, in combination with the example of pointer position in Figure 1a, further demonstrates an aspect with respect to the
10 preferred resetting of FIFO memory 12. Particularly, the pointer position in Figure 1a depicts a preferable spacing of write pointer PTR_{WT} and read pointer PTR_{RD} upon reset, which may occur at start-up or as a response following a level of FIFO fullness, which is detected according to the preferred embodiments as detailed later. Alternatively, the preferable spacing of write pointer PTR_{WT} and read pointer PTR_{RD} upon reset may occur
15 after a pointer collision, where such a collision may be detected in various forms, including also by monitoring shift registers SR_{WT} and SR_{RD} , as further borne out in U.S. Patent Application _____, entitled "First-In First-Out Memory System With A Single Bit Indication Of An Addressed Word Location" (TI-36900), filed on the same date as the present application, and hereby incorporated herein by reference. In any event, in
20 the preferred embodiment, for a FIFO having M word storage locations, then upon reset, read pointer PTR_{RD} and write pointer PTR_{WT} are spaced apart a distance of $M/2$ storage locations, as may be achieved through control of controller 16. Thus, the reset sequence of bits in read shift register SR_{RD} is offset from the reset sequence of bits in write shift register SR_{WT} by a distance of $M/2$. This separation, along with the expectation that over time the
25 frequency of each pointer clock is approximately the same as the other pointer clock, reduces the chance that either pointer will advance to encroach upon or collide with the other. With this knowledge of the preferred reset positioning, one skilled in the art may ascertain various fashions to ensure that the first four reads are indicated as invalid. However, once read pointer reaches PTR_{RD} reaches storage location $SL4$ in a first instance
30 following a reset, and as shown in Figure 1a, and assuming that no reset from a collision

then occurs with write pointer PTR_{WT} , that is, assuming write pointer PTR_{WT} has advanced such as also shown by way of example in Figure 1b, then the next read will be of valid data. Once more, one skilled in the art may ascertain various fashions to ensure that such reads are indicated as valid.

5 [0028] Figure 2 illustrates system 10 of Figure 1a (and 1b) with additional aspects directed to detecting valid data fullness, either in the form of near-full or near-empty status, in FIFO memory 12. For sake of distinction, the system shown in Figure 2 is referred to as system 10₁. System 10₁ includes the same components of system 10 from Figure 1a, where for sake of convenience and understanding the reference numbers for
 10 these same items are carried forward from Figure 1a into Figure 2. Thus, the reader is referred to the previous discussion for details on such aspects. Looking then to the additional aspects of system 10₁ over system 10, system 10₁ includes a FIFO fullness detecting circuit 18₁. In the preferred embodiment, FIFO fullness detecting circuit 18₁ consists of circuitry that performs its analysis through only a single stage of logic, that is,
 15 selected bits are connected to logic where the serial path through that logic only passes through a single gate to provide an indication of FIFO fullness. More particularly, in the illustrated and preferred embodiment, the single stage consists of one logic gate, namely, an AND gate 18_{AND1}, with inputs 18_{A_IN1} and 18_{A_IN2} connected to like-positioned bit locations in write and read shift registers SR_{WT} and SR_{RD} , respectively. Specifically, a first
 20 input 18_{A_IN1} is connected to bit location $SR_{WT}[7]$ and a second input 18_{A_IN2} is connected to bit location $SR_{RD}[7]$. The output of AND gate 18_{AND1} provides a valid signal, designated as V. The valid signal, V, corresponds to a second signal of FIFO fullness detecting circuit 18₁, where that signal is shown in Figure 2 as \bar{F}/E and is provided by the state of bit location $SR_{RD}[6]$, that is, the location that immediately follows the location that is
 25 connected to input 18_{A_IN2} of AND gate 18_{AND1}. Thus, when the valid signal, V, is asserted high, then for sake of the indication of fullness detection, the \bar{F}/E signal is considered valid. Moreover, and as demonstrated later, when valid the \bar{F}/E signal indicates that FIFO memory 12 is approaching either a near-full or near-empty status. Specifically, an

output of $\bar{F}/E=0$, when valid, indicates that FIFO memory 12 is near full, and an output of $\bar{F}/E=1$, when valid, indicates that FIFO memory 12 is near empty.

[0029] The binary states stored in write shift register SR_{WT} and read shift register SR_{RD} of Figure 2 differ slightly from those shown in Figure 1a. Specifically, recall that earlier it is stated that each shift register, under the preferred embodiment, stores at least one binary value of one. In the example of Figure 2, two such binary values of one are stored in each shift register, with the leading bit position, as considered in terms of the direction of shifting for each register, being the bit that corresponds to the pointer for that shift register. Thus, with respect to write shift register SR_{WT} , the binary value of one in its leading bit location, namely, $SR_{WT}[4]$, corresponds to write pointer PTR_{WT} . With respect to read shift register SR_{RD} , it has a binary value of one in locations $SR_{RD}[0]$ and $SR_{RD}[7]$; however, recall that it shifts bits from its MSB to its LSB and, thus, in terms of this rotational shifting, the bit at location $SR_{RD}[0]$ leads the one behind it at $SR_{RD}[7]$ and, thus, the binary value of one at bit location $SR_{RD}[0]$ corresponds to read pointer PTR_{RD} . The effect of the trailing binary one in each of shift registers SR_{WT} and SR_{RD} , as shown in bit locations $SR_{WT}[3]$ and $SR_{RD}[7]$ in Figure 2, is further appreciated from the remaining discussion in this document.

[0030] Figure 3 illustrates sequential operations of the preferred embodiment of system 10₁ of Figure 2 where read shift register SR_{RD} advances toward write shift register SR_{WT} as FIFO memory 12 approaches an empty state. For sake of simplifying the drawing, the only structures shown in Figure 3 are shift registers SR_{WT} and SR_{RD} , and they are shown horizontally for sake of illustrating a time sequence downward along the Figure. Particularly, in the example of Figure 3, write shift register SR_{WT} is shown to maintain a single state of binary values designated SR_{WT} , where that state includes a leading binary value of one in location $SR_{WT}[0]$, followed in shifting time by a binary one in location $SR_{WT}[7]$. In contrast, read shift register SR_{RD} is shown to sequence through seven different states, which commence with a binary state shown as SR_{RD_1} and which is followed by six additional cycles of read clock CLK_{RD} . In binary state SR_{RD_1} , the leading binary one stored

in read shift register SR_{RD} is in location $SR_{RD}[1]$ followed by a single trailing binary value of one stored in location $SR_{RD}[0]$. Thus, for each successive cycle of CLK_{RD} , these two binary ones advance one position toward the MSB, which in Figure 3 is to the left. Further, because the leading binary value of one in read shift register SR_{RD} corresponds to read pointer PTR_{RD} , then one skilled in the art should appreciate that Figure 3 demonstrates the advancement of read pointer PTR_{RD} toward write pointer PTR_{WT} , which corresponds to an example of the emptying of the valid data of FIFO memory 12 as each read occurs. Moreover, when read pointer PTR_{RD} gets within a certain proximity of write pointer PTR_{WT} , then the preferred embodiment detects this near-empty status, as further discussed below.

[0031] Looking to Figure 3 in combination with Figure 2, one skilled in the art will appreciate the resulting signals that are provided by FIFO fullness detecting circuit 18₁. Specifically, for each of sequences SR_{RD_1} through SR_{RD_6} , the valid signal V output of AND gate 18_{AND1} is low and, thus, this indicates that the \bar{F}/E indication from bit location $SR_{RD}[6]$ is to be considered invalid. However, for sequence SR_{RD_7} , the valid signal V output of AND gate 18_{AND1} is high and, thus, this indicates that the \bar{F}/E indication from bit location $SR_{RD}[6]$ is to be considered valid. Also in sequence SR_{RD_7} , the binary value at bit location $SR_{RD}[6]$ provides the \bar{F}/E signal and is one, and recall from earlier that such a value is defined to indicate a near-empty status. Accordingly, system 10₁ provides a detection of such a status through the indication of the \bar{F}/E and V signals, and in response to that status various actions may be taken as may be ascertained by one skilled in the art.

[0032] Figure 4 illustrates sequential operations of the preferred embodiment of system 10₁ of Figure 2 where write shift register SR_{WT} advances toward read shift register SR_{RD} as FIFO memory 12 approaches a full state. As was the case for Figure 3, Figure 4 only illustrates shift registers SR_{WT} and SR_{RD} in a horizontal orientation and with time shifting occurring to the left. In the example of Figure 4, read shift register SR_{RD} is shown to maintain a single state of binary values designated SR_{RD} , where in contrast write shift

register SR_{WT} is shown to sequence through seven different states, which commence with a binary state shown as SR_{WT_1} that is followed by six additional cycles of write clock CLK_{WT} . In binary state SR_{WT_1} , the leading binary one stored in write shift register SR_{WT} is in location $SR_{WT}[1]$ followed by a single trailing binary value of one stored in location $SR_{WT}[0]$. Thus, for each successive cycle of write clock CLK_{WT} , these two binary ones advance one position toward the MSB. Further, because the leading binary value of one in write shift register SR_{WT} corresponds to write pointer PTR_{WT} , then one skilled in the art should appreciate that Figure 4 demonstrates the advancement of write pointer PTR_{WT} towards read pointer PTR_{RD} , which corresponds to an example of the filling of the valid data of FIFO memory 12 as each write occurs. Moreover, when write pointer PTR_{WT} gets within a certain proximity of read pointer PTR_{RD} , then the preferred embodiment detects this near-full status, as further discussed below.

[0033] Looking to Figure 4 in combination with Figure 2, one skilled in the art will appreciate the resulting signals that are provided by FIFO fullness detecting circuit 18. Specifically, for each of sequences SR_{WT_1} through SR_{WT_6} , the valid signal V output of AND gate 18_{AND1} is low and, thus, this indicates that the \bar{F}/E indication from bit location $SR_{RD}[6]$ is to be considered invalid. However, for sequence SR_{WT_7} , the valid signal V output of AND gate 18_{AND1} is high and, thus, this indicates that the \bar{F}/E indication from bit location $SR_{RD}[6]$ is to be considered valid. Also in sequence SR_{WT_7} , the binary value at bit location $SR_{RD}[6]$ provides the \bar{F}/E signal and is zero, and recall from earlier that such a value is defined to indicate a near-full status. Accordingly, system 10 provides a detection of such a status through the indication of the \bar{F}/E and V signals, and again various actions may be taken as may be ascertained by one skilled in the art.

[0034] The preceding demonstrates a preferred embodiment that operates to detect a near-full or near-empty status of a FIFO system. Note that the preferred embodiment achieves its result with a key benefit over the prior art. Specifically, the use of read and write shift registers, advanced by respective read and write clock cycles, permits an instantaneous analysis of bits as they exist at a same time in both registers. As such, there

is no need to capture a multiple-bit pointer vector in one clock domain and to take that vector into the clock domain of the other pointer. Further, the detection of a preferred embodiment may be implemented in a single logic stage, that is, the signal analysis passes serially through only a single logic gate, which in the example of Figure 2 is a single AND gate, while additional embodiments below show additional gates, but those gates operate in parallel and without feedback so there is no or minimal additional delay or instability which might give rise to delay in the resulting indication of FIFO status. In either case, therefore, the FIFO fullness detection may be achieved with considerably less complexity as compared to the prior art, thereby reducing device size and cost. As another benefit of the preferred embodiment, it may be modified to provide additional embodiments, where certain examples of such embodiments are shown below. As still another benefit, given the asynchronous nature of read clock CLK_{RD} and write clock CLK_{WT} , the overlap between two binary ones in the respective shift registers may be for a short period of time, where that shortness in the prior art of an overlap of vector pointers required considerable complexity to accurately detect. In contrast, all that is required in the preferred embodiment is the triggering of a logic gate. Note also in this regard and for purposes of additional response to the detected collision, the high output of the detecting AND gate may be connected to additional circuitry (not shown) that may be included in detecting circuit 18₁. For example, the output of the detecting AND gate may be connected as a clear input to two cascaded flip flops, in which case a FIFO fullness indication, even if detected by the AND gate for a very short period of time, is then effectively extended in time as it is clocked through the cascaded flip flops. With this extended asserted signal, FIFO memory 12 may be reset in response to the detected status, such as by again positioning the binary sequences in the shift registers in the positions indicated in Figure 1a and also marking the data in FIFO memory 12 invalid. Still other synchronization techniques in response to the detected collision may be ascertained by one skilled in the art.

[0035] Figure 5 illustrates a system 10₂ as an alternative to system 10₁ of Figure 2, where system 10₂ shares various aspects of system 10₁ and the reference numbers for such aspects are carried forward from Figure 2 into Figure 5 and the reader is assumed familiar with the earlier discussion of such items. Looking then to the differences in system 10₂ as

compared to system 10₁, system 10₂ includes a FIFO fullness detecting circuit 18₂. In the preferred embodiment, FIFO fullness detecting circuit 18₂ includes the same two-input AND gate 18_{AND1} having an input connected to bit locations SR_{WT}[7] and SR_{RD}[7] and providing an output valid signal, V. However, two distinctions are shown in system 10₂ as compared to system 10₁. First, an \bar{F}/E signal is again provided, but in system 10₂ it is provided by the state of bit location SR_{RD}[5], that is, the location that follows two bits following the location that is connected to input 18_{A_IN2} of AND gate 18_{AND1}. Here again, when the valid signal, V, is asserted high, then \bar{F}/E signal is considered valid, and the \bar{F}/E signal indicates that FIFO memory 12 is approaching either a near-full status if $\bar{F}/E=0$ or a near-empty status if $\bar{F}/E=1$. As an additional difference between systems 10₂ and 10₁, each shift register in system 10₂ is loaded with a sequence that includes three contiguous binary ones, as opposed to two contiguous binary ones in system 10₁. In addition, in the illustrated example of system 10₂, the middle binary one for each shift register corresponds to the pointer. Thus, with respect to write shift register SR_{WT}, its middle binary one is at location SR_{WT}[4] and it corresponds to write pointer PTR_{WT}, and with respect to read shift register SR_{RD}, its middle binary one is at location SR_{RD}[0] and it corresponds to read pointer PTR_{RD}.

[0036] Figure 6 illustrates sequential operations of the preferred embodiment of system 10₂ of Figure 5 where read shift register SR_{RD} advances toward write shift register SR_{WT} as FIFO memory 12 approaches an empty state, where again to simplify the drawing Figure 6 illustrates only shift registers SR_{WT} and SR_{RD}. Also in the example of Figure 6, write shift register SR_{WT} is shown to maintain a single state of binary values designated as SR_{WT}, where that state includes a leading binary value of one in location SR_{WT}[1], followed in shifting time by two binary ones, one at location SR_{WT}[0] and corresponding to write pointer PTR_{WT} and another at location SR_{WT}[7]. In contrast, read shift register SR_{RD} is shown to sequence through six different states, SR_{RD_1} through SR_{RD_6}, each responsive to a cycle of read clock CLK_{RD}. In binary state SR_{RD_1}, the leading binary one stored in read shift register SR_{RD} is in location SR_{RD}[2] followed by two trailing binary value of ones, the

first stored in location $SR_{RD}[1]$ and corresponding to read pointer PTR_{RD} and the second stored in location $SR_{RD}[0]$. Thus, for each successive cycle of read clock CLK_{RD} , these three binary ones advance one position toward the MSB, which consistent with the remaining convention in this document is to the left. As with earlier examples, because the middle
 5 binary value of one in read shift register SR_{RD} corresponds to read pointer PTR_{RD} , Figure 6 demonstrates the advancement of read pointer PTR_{RD} toward write pointer PTR_{WT} and, hence, toward a near-empty state of FIFO memory 12.

[0037] Looking to Figure 6 in combination with Figure 5, one skilled in the art will appreciate the resulting signals that are provided by FIFO fullness detecting circuit 18₂.
 10 Specifically, for each of sequences SR_{RD_1} through SR_{RD_5} , the V output of AND gate 18_{AND1} is low and, thus, this indicates that the \bar{F}/E signal output by bit $SR_{RD}[5]$ is to be considered invalid. However, for sequence SR_{RD_6} , the V output of AND gate 18_{AND1} is high and, thus, this indicates that the \bar{F}/E signal output from bit $SR_{RD}[5]$ is to be considered valid. Further in this regard, in sequence SR_{RD_6} , the binary value at bit
 15 location $SR_{RD}[5]$ is one, thereby producing an \bar{F}/E signal equal to one. Further, recall from earlier that a high \bar{F}/E output is defined to indicate a near-empty status. Accordingly, system 10₂ provides a detection of such a status through the indication of the \bar{F}/E and V signals, and in response to that status various actions may be taken as may be ascertained by one skilled in the art.

20 [0038] Before proceeding, a few additional observations are noteworthy with respect to system 10₂ of Figure 5 as compared to system 10₁ of Figure 2. System 10₁, using only two binary ones in each shift register sequence and tapping the \bar{F}/E signal from $SR_{RD}[6]$ represents an implementation that may assume certain ideal conditions. In many circuits, however, there will be delays in the circuit operation. These delays may be more properly
 25 accounted for using system 10₂. For example, consider the transition between case 1 and case 2, shown in the following Table 1:

7	6	5	4	3	2	1	0	Bit location	Case
1	1	0	0	0	0	0	0	SR _{RD}	Case 1
0	1	1	0	0	0	0	0	SR _{WT}	Case 1
1	0	0	0	0	0	0	1	SR _{RD}	Case 2
1	1	0	0	0	0	0	0	SR _{WT}	Case 2

Table 1

In Case 1, and according to system 10₁, the output of AND gate 18_{AND1} is low due to its low input from location SR_{WT}[7] and, hence, the bit at location SR_{RD}[6] is considered invalid. However, assume at or near the same time, both shift registers advance from Case 1 to

5 Case 2. In response, the output of AND gate 18_{AND1} will transition from low to high, while at the same time the value of \bar{F}/E signal from location SR_{RD}[6] will be transitioning from high to low. Thus, there may exist a small amount of time when the valid signal might be high before the \bar{F}/E signal is detected as low, thereby potentially providing an erroneous indication. System 10₂ of Figure 5 avoids this possibility by providing three contiguous

10 ones and an additional offset of one more bit location between the bit location 7 of the AND input and the bit location SR_{RD}[5] of the \bar{F}/E signal. More particularly, in this latter embodiment, the valid signal, V, will go high at least one write clock cycle after the location SR_{RD}[5] bit (i.e., the \bar{F}/E signal) has already transitioned low, thereby causing the \bar{F}/E signal to be properly interpreted once the valid signal, V, goes high. Thus, system

15 10₂ may prove more desirable in certain implementations.

[0039] Figure 7 illustrates sequential operations of the preferred embodiment of system 10₂ of Figure 5 where write shift register SR_{WT} advances toward read shift register SR_{RD} as FIFO memory 12 approaches a full state, where again as simplified the drawing depicts only shift registers SR_{WT} and SR_{RD}. In the example of Figure 7, read shift register

SR_{RD} is shown to maintain a single state of binary values designated as SR_{RD}, where that state includes a leading binary value of one in location SR_{RD}[1], followed in shifting time by two binary ones, one at location SR_{RD}[0] and corresponding to read pointer PTR_{RD} and another at location SR_{RD}[7]. In contrast, write shift register SR_{WT} is shown to sequence
 5 through six different states, SR_{WT,1} through SR_{WT,6}, each responsive to a cycle of write clock CLK_{WT} discussed above. In binary state SR_{WT,1}, the leading binary one stored in write shift register SR_{WT} is in location SR_{WT}[2] followed by two time trailing binary value of ones, the first stored in location SR_{WT}[1] and corresponding to write pointer PTR_{WT} and the second stored in location SR_{WT}[0]. Thus, for each successive cycle of CLK_{WT}, these
 10 three binary ones advance one position toward the MSB, again shown to the left. As with earlier examples, because the middle binary value of one in write shift register SR_{WT} corresponds to write pointer PTR_{WT}, Figure 7 demonstrates the advancement of write pointer PTR_{WT} toward read pointer PTR_{RD} and, hence, toward a near-full state of FIFO memory 12.

15 [0040] Looking to Figure 7 in combination with Figure 5, the resulting signals provided by FIFO fullness detecting circuit 18₂ are readily understood. For each of sequences SR_{WT,1} through SR_{WT,5}, the V output of AND gate 18_{AND1} is low and, thus, this indicates that the \bar{F}/E signal from location SR_{RD}[5] is to be considered invalid. However, for sequence SR_{WT,6}, the V output of AND gate 18_{AND} is high and, thus, this indicates that
 20 the \bar{F}/E signal from location SR_{RD}[5] is to be considered valid. Also in sequence SR_{WT,6}, the binary value at bit location SR_{RD}[5] (at the top of Figure 7) is zero, thereby providing the value of \bar{F}/E equal to zero. Further, recall from earlier that a low \bar{F}/E output is defined to indicate a near-full status. Accordingly, system 10₂ provides a detection of such a status through the indication of the \bar{F}/E and V signals, and in response to that status
 25 various actions may be taken as may be ascertained by one skilled in the art.

[0041] Figure 8 illustrates a system 10₃ as an alternative to system 10₂ of Figure 5, or which may be combined with system 10₂ for additional fullness detection. System 10₃ shares various aspects of system 10₂ and again the reference numbers for such aspects are

carried forward from Figure 5 into Figure 8. Looking then to the differences in system 10₃ as compared to system 10₂, system 10₃ includes a FIFO mid-fullness detecting circuit 18₃ which, as its name suggests, is operable to detect when FIFO memory 12 is halfway full. In the preferred embodiment, FIFO mid-fullness detecting circuit 18₃ includes a two-input

5 AND gate 18_{AND2} having one input 18_{A2_IN1} connected to bit location SR_{WT}[3] and another input 18_{A2_IN2} connected to bit location SR_{RD}[7], where AND gate 18_{AND2} provides a mid-full signal, MF, at its output. In addition, mid-fullness detecting circuit 18₃ includes an

10 AND gate 18_{AND3}, having an input 18_{A3_IN1} connected to bit location SR_{RD}[0] and an inverted input 18_{A3_IN2} connected to bit location SR_{RD}[1]. The output of AND gate 18_{AND3} provides an output valid signal, V, which when asserted indicates that the MF signal output by AND gate 18_{AND2} is valid. Also with respect to the MF signal, when it is asserted high and is valid, it indicates that FIFO memory 12 is half full, that is, for its M word storage locations, M/2 of those locations store valid unread data. However, if MF is not valid or not asserted, then no half-full status is detected. These signals and operation

15 are further appreciated below.

[0042] Figure 9 illustrates sequential operations of the preferred embodiment of system 10₃ of Figure 8 where read shift register SR_{WT} advances and write shift register remains in an un-shifted state, with each starting with the state also illustrated in Figure 8. Thus, with respect to write shift register SR_{WT}, it has a binary value of one at its location

20 SR_{WT}[3], which corresponds to write pointer PTR_{WT}, and which is preceded in shifting time by a binary one at location SR_{WT}[4] and is followed in shifting time by a binary one at location SR_{WT}[2]. Read shift register SR_{RD} is shown in Figure 9 to advance through a sequence of eight shifts SR_{RD_1} through SR_{RD_8}, with each shift corresponding to a cycle of read clock CLK_{RD}. In sequence SR_{RD_1}, read shift register SR_{RD} has a binary value of one at

25 its location SR_{RD}[2], which corresponds to read pointer PTR_{RD}, and which is preceded in shifting time by a binary one at location SR_{RD}[3] and is followed in shifting time by a binary one at location SR_{RD}[1]. Thus, as read shift register SR_{RD} shifts its binary values, it corresponds to the advancement of read pointer PTR_{RD} toward write pointer PTR_{WT}. As shown below, once the two pointers are M/2 word slot locations apart, thereby placing

FIFO memory 12 in a mid-full state, FIFO mid-fullness detecting circuit 18₃ detects such a status.

[0043] Looking to Figure 9 in combination with Figure 8, the resulting signals provided by FIFO mid-fullness detecting circuit 18₃ are readily understood. For each of sequences SR_{RD,1} through SR_{RD,5} and SR_{RD,7} through SR_{RD,8}, the V output of AND gate 18_{AND3} is low and, thus, this indicates that the MF output from AND gate 18_{AND2} is to be considered invalid. However, for sequence SR_{RD,6}, the V output of AND gate 18_{AND3} is high and, thus, this indicates that the MF output from AND gate 18_{AND2} is to be considered valid. Also in sequence SR_{RD,6}, the binary values at bit locations SR_{WT}[3] and SR_{RD}[7] are both one, which are provided as inputs to AND gate 18_{AND2}, thereby causing that gate to produce a high MF signal. Thus, at this point, the MF signal is valid as indicated by AND gate 18_{AND3}, and when valid and high recall from earlier that such an indication is defined to indicate a mid-full status. Accordingly, system 10₃ provides a detection of such a status and that indication may be used as determined by one skilled in the art.

[0044] Figure 10 illustrates a system 10₄ as an alternative to system 10₁ of Figure 2, where once again system 10₄ shares various aspects of system 10₁ and the reference numbers for such aspects are carried forward from Figure 2 into Figure 10. Looking then to the differences in system 10₄ as compared to system 10₁, system 10₄ includes a FIFO fullness detecting circuit 18₄. In the preferred embodiment, FIFO fullness detecting circuit 18₄ includes two AND gates. A first AND gate 18_{AND4} has one input connected to bit location SR_{WT}[7] and another input connected to bit location SR_{RD}[6]. The output of AND gate 18_{AND4} provides an NE signal, which when asserted high indicates a near-empty status for FIFO memory 12. A second AND gate 18_{AND5} has one input connected to bit location SR_{WT}[6] and another input connected to bit location SR_{RD}[7]. The output of AND gate 18_{AND5} provides an NF signal, which when asserted high indicates a near-full status for FIFO memory 12.

[0045] The operation of system 10₄ of Figure 10 is readily understood from the illustration of Figure 10 as well as the numerous alternative embodiments described

above. In general, each shift register SR_{WT} and SR_{RD} stores a known binary pattern. For each cycle of the appropriate one of the read or write clocks CLK_{RD} and CLK_{WT} , the corresponding shift register advances its pattern. In the example of Figure 10, each pattern stores only a single binary value of one, with the remaining bits storing a binary value of zero. The binary one in each shift register corresponds to the pointer for that register, that is, the binary one at location $SR_{WT}[4]$ in Figure 10 corresponds to write pointer PTR_{WT} indicating word storage location SL_4 , and the binary one at location $SR_{RD}[0]$ in Figure 10 corresponds to read pointer PTR_{RD} indicating word storage location SL_0 . In response to the advancement of each pattern as the respective shift register shifts, FIFO fullness detecting circuit 18₄ includes sufficient circuitry to monitor the placement of one shift register's bits in time relative to the placement of the other shift register's bits in time. Thus, if over time write shift register SR_{WT} advances at a greater rate than read shift register SR_{RD} , then the binary value of one in write shift register SR_{WT} at some point will become positioned at one bit location behind the binary value of one in read shift register SR_{RD} . If this occurs when the value of one in write shift register SR_{WT} is positioned at location $SR_{WT}[6]$ and the value of one in read shift register SR_{RD} is positioned at location $SR_{RD}[7]$, then AND gate 18_{AND5} will assert the NF signal, thereby indicating a near-full status of FIFO memory 12. Conversely, if over time read shift register SR_{RD} advances at a greater rate than write shift register SR_{WT} , then the binary value of one in read shift register SR_{RD} at some point will become positioned at one bit location behind the binary value of one in write shift register SR_{WT} . If this occurs when the value of one in read shift register SR_{RD} is positioned at location $SR_{RD}[6]$ and the value of one in write shift register SR_{WT} is positioned at location $SR_{WT}[7]$, then AND gate 18_{AND4} will assert the NE signal, thereby indicating a near-empty status of FIFO memory 12.

[0046] From the above, one skilled in the art that the scope of the present inventive embodiments span numerous examples. In each, a known predetermined shifting binary pattern is used to correspond to a FIFO pointer. With knowledge of that pattern, circuitry is included to detect the relative position of one FIFO pointer (e.g., write) with respect to the other FIFO pointer (e.g., read). The above examples illustrate that a differing number of binary ones and zeroes may be used to provide differing patterns. With more than one

binary one in a given pattern, then a same bit position in each shift register may be used to provide a basis of comparison as one pattern approaches, in time, the other, such as shown in systems 10₁ and 10₂. Indeed, the use of more than one binary value of one in the shift patterns in these examples provides in effect history information, relative to the binary value of one that corresponds to a pointer. This history provides a basis from which a given state of the two shift registers may be analyzed to determine which FIFO pointer recently advanced toward the other. Alternatively, even with a single binary one in each shift register, such as shown for system 10₄, the passage of one shift pattern relative to the other in time may be detected, provided that the detection is based on a different bit location in one shift register versus the other. Lastly, system 10₃ illustrates, by way of example, that either alone or in combination with other embodiments, the present inventive scope also provides for mid-full detection in the FIFO. Further, still other embodiments may be implemented with different logic gates. In addition to the benefit of providing many alternatives, the preferred embodiments provide various other benefits. As an example, with the preferred embodiments, both the read and write pointers may be represented by respective shift registers, where in those registers a single binary state (e.g., one) corresponds to the FIFO word storage location indicated by the respective word pointer. The correspondence between the single shifted binary one and the respective FIFO pointer may be direct whereby the binary one provides the FIFO pointer or indirect whereby the binary one tracks the FIFO pointer, such as being advanced each time the FIFO pointer is advanced (or once for every R times the FIFO pointer is advanced). Moreover, note that the correspondence between the single shifted binary one and the respective FIFO pointer may involve an offset between the two. In other words, the preceding has demonstrated examples where the binary value of one has a same bit location in a shift register as the corresponding word storage location in FIFO memory 12, that is, at a bit location m in a shift register corresponds to a pointer indication of word storage location m in FIFO memory 12. Alternatively, the selected value of one (or zero) may still correspond to a word storage location with a known offset as between the bit locations in the shift register and the word storage location in FIFO memory 12. As another example of the inventive benefits, with the shifted binary value and pointer

correspondence, an additional aspect permits comparison of the binary states in the two shift registers so that the relative advancement in time, of the corresponding pointers, may be evaluated so as to detect near-full, near-empty, or mid-full status of the FIFO being operated according to those pointers. As still another example, the detection may be achieved using a minimal amount of logic, and with signals passing serially through only a single stage of logic (e.g., AND) and without requiring a complex capture of an entire pointer vector in one clock domain and the transfer of that vector into the other pointer's domain so as to detect FIFO status. As yet another example, the preferred embodiments are readily scalable for different sized FIFOs having differing number of word storage locations and differing numbers of word sizes. In all such approaches, further benefits are realized in that the overall size, complexity, power consumption, and cost of the FIFO and hence the system using the FIFO is reduced. As another example, the preferred embodiments include variations described above, where certain of those variations may be further applied within the illustrated embodiments. Still further, other examples exist and/or may be ascertained by one skilled in the art. For example, while the binary value of one has been shown to be the minority value in each shift register and corresponding to the location of the respective word storage location, a simple complement may be made to the above illustrations where the majority of the bits in each shift register are binary ones while a binary zero, with or without additional zeroes, corresponds to the pointer location of the respective word storage location in FIFO memory 12. Thus, these examples provide yet other bases from which one skilled in the art may ascertain yet other benefits and variations, and indeed while the present embodiments have been described in detail, various substitutions, modifications or alterations could be made to the descriptions set forth above without departing from the inventive scope which is defined by the following claims.